TAIWAN SEMICONDUCTOR

RoHS COMPLIANCE

# TSM3454

30V N-Channel MOSFET

**SOT-26**


**Pin Definition:**
1. Drain 6. Drain
2. Drain 5, Drain
3. Gate 4. Source

## PRODUCT SUMMARY

| $V_{DS}$ (V) | $R_{DS(on)}$(mΩ) | $I_D$ (A) |
|---|---|---|
| 30 | 60 @ $V_{GS}$ = 10V | 4.5 |
| | 85 @ $V_{GS}$ = 4.5V | 3.8 |

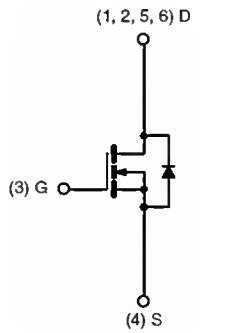
## Features

- Advance Trench Process Technology
- High Density Cell Design for Ultra Low On-resistance

## Application

- Load Switch
- PA Switch

## Block Diagram




N-Channel MOSFET

## Ordering Information

| Part No. | Package | Packing |
|---|---|---|
| TSM3454CX6 RF | SOT-26 | 3Kpcs / 7" Reel |

## Absolute Maximum Rating (Ta = 25°C unless otherwise noted)

| Parameter | | Symbol | Limit | Unit |
|---|---|---|---|---|
| Drain-Source Voltage | | $V_{DS}$ | 30 | V |
| Gate-Source Voltage | | $V_{GS}$ | ±20 | V |
| Continuous Drain Current | | $I_D$ | 4.5 | A |
| Pulsed Drain Current | | $I_{DM}$ | ±20 | A |
| Continuous Source Current (Diode Conduction)[a,b] | | $I_S$ | 1.7 | A |
| Maximum Power Dissipation | Ta = 25°C | $P_D$ | 2.0 | W |
| | Ta = 75°C | | 1.3 | |
| Operating Junction Temperature | | $T_J$ | +150 | °C |
| Operating Junction and Storage Temperature Range | | $T_J$, $T_{STG}$ | -55 to +150 | °C |

## Thermal Performance

| Parameter | Symbol | Limit | Unit |
|---|---|---|---|
| Junction to Case Thermal Resistance | $R\Theta_{JF}$ | 62.5 | °C/W |
| Junction to Ambient Thermal Resistance (PCB mounted) | $R\Theta_{JA}$ | 110 | °C/W |

Notes:

a. Pulse width limited by the Maximum junction temperature

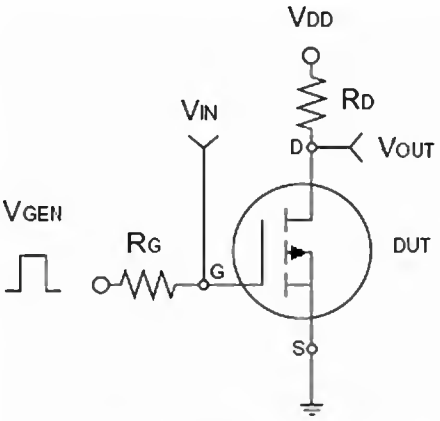
b. Surface Mounted on FR4 Board, t ≤ 5 sec.

# TSM3454
30V N-Channel MOSFET

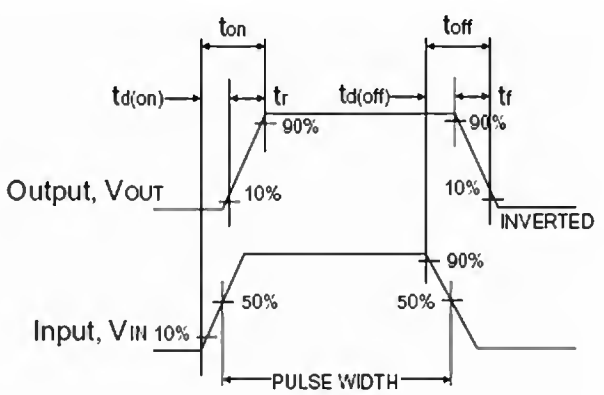
## Electrical Specifications (Ta = 25°C unless otherwise noted)

| Parameter | Conditions | Symbol | Min | Typ | Max | Unit |
|---|---|---|---|---|---|---|
| **Static** | | | | | | |
| Drain-Source Breakdown Voltage | $V_{GS}$ = 0V, $I_D$ = 250μA | $BV_{DSS}$ | 30 | -- | -- | V |
| Gate Threshold Voltage | $V_{DS}$ = $V_{GS}$, $I_D$ = 250μA | $V_{GS(TH)}$ | 1 | -- | 3 | V |
| Gate Body Leakage | $V_{GS}$ = ±20V, $V_{DS}$ = 0V | $I_{GSS}$ | -- | -- | ±100 | nA |
| Zero Gate Voltage Drain Current | $V_{DS}$ = 30V, $V_{GS}$ = 0V | $I_{DSS}$ | -- | -- | 1.0 | μA |
| On-State Drain Current | $V_{DS}$ ≥ 5V, $V_{GS}$ = 10V | $I_{D(ON)}$ | 15 | -- | -- | A |
| Drain-Source On-State Resistance | $V_{GS}$ = 10V, $I_D$ = 4.5A | $R_{DS(ON)}$ | -- | 48 | 60 | mΩ |
| | $V_{GS}$ = 4.5V, $I_D$ = 3.8A | | -- | 70 | 85 | |
| Forward Transconductance | $V_{DS}$ = 10V, $I_D$ = 4.5A | $g_{fs}$ | -- | 10 | -- | S |
| Diode Forward Voltage | $I_S$ = 1.7A, $V_{GS}$ = 0V | $V_{SD}$ | -- | -- | 1.2 | V |
| **Dynamic**[b] | | | | | | |
| Total Gate Charge | $V_{DS}$ = 15V, $I_D$ = 4.5A, $V_{GS}$ = 10V | $Q_g$ | -- | 4.2 | 7 | nC |
| Gate-Source Charge | | $Q_{gs}$ | -- | 1.9 | -- | |
| Gate-Drain Charge | | $Q_{gd}$ | -- | 1.35 | -- | |
| Input Capacitance | $V_{DS}$ = 15V, $V_{GS}$ = 0V, f = 1.0MHz | $C_{iss}$ | -- | 555 | -- | pF |
| Output Capacitance | | $C_{oss}$ | -- | 120 | -- | |
| Reverse Transfer Capacitance | | $C_{rss}$ | -- | 60 | -- | |
| **Switching**[c] | | | | | | |
| Turn-On Delay Time | $V_{DD}$ = 15V, $R_L$ = 15Ω, $I_D$ = 1A, $V_{GEN}$ = 10V, $R_G$ = 6Ω | $t_{d(on)}$ | -- | 9 | 20 | nS |
| Turn-On Rise Time | | $t_r$ | -- | 7.5 | 18 | |
| Turn-Off Delay Time | | $t_{d(off)}$ | -- | 17 | 35 | |
| Turn-Off Fall Time | | $t_f$ | -- | 5.2 | 12 | |

Notes:
a. pulse test: PW ≤300μS, duty cycle ≤2%
b. For DESIGN AID ONLY, not subject to production testing.
b. Switching time is essentially independent of operating temperature.

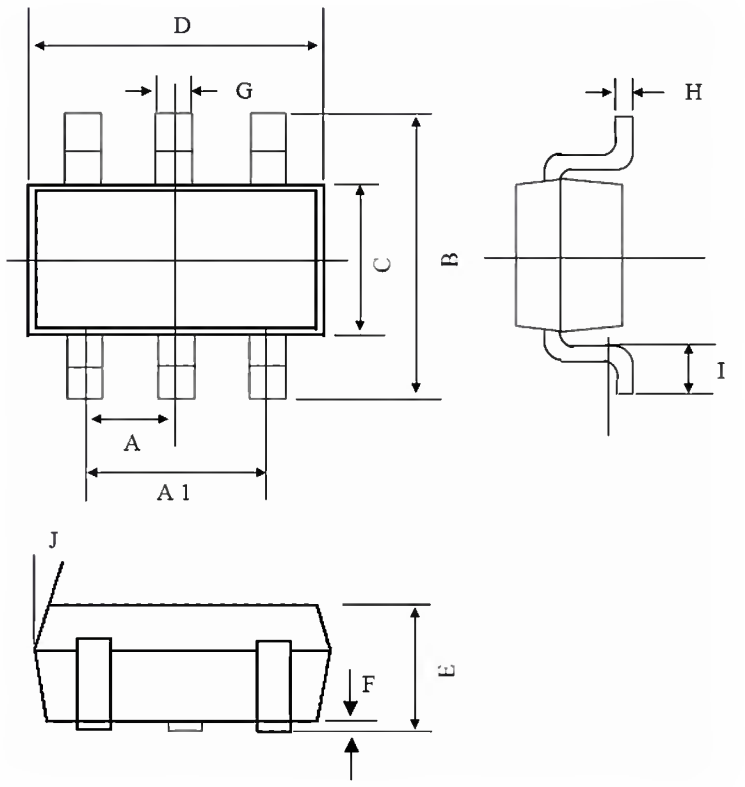



Switching Test Circuit



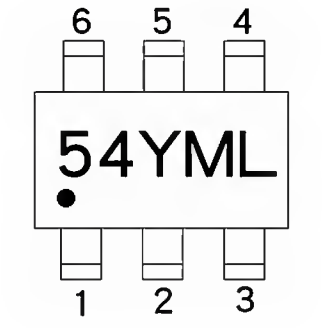

Switchin Waveforms

## SOT-26 Mechanical Drawing




| SOT-26 DIMENSION | | | | | | |
|---|---|---|---|---|---|---|
| DIM | MILLIMETERS | | | INCHES | | |
| | MIN | TYP | MAX | MIN | TYP | MAX |
| A | 0.95 BSC | | | 0.0374 BSC | | |
| A1 | 1.9 BSC | | | 0.0748 BSC | | |
| B | 2.60 | 2.80 | 3.00 | 0.1024 | 0.1102 | 0.1181 |
| C | 1.40 | 1.50 | 1.70 | 0.0551 | 0.0591 | 0.0669 |
| D | 2.80 | 2.90 | 3.10 | 0.1101 | 0.1142 | 0.1220 |
| E | 1.00 | 1.10 | 1.20 | 0.0394 | 0.0433 | 0.0472 |
| F | 0.00 | -- | 0.10 | 0.00 | | 0.0039 |
| G | 0.35 | 0.40 | 0.50 | 0.0138 | 0.0157 | 0.0197 |
| H | 0.10 | 0.15 | 0.20 | 0.0039 | 0.0059 | 0.0079 |
| I | 0.30 | -- | 0.60 | 0.0118 | -- | 0.0236 |
| J | 5° | -- | 10° | 5° | -- | 10° |

## Marking Diagram




**54** = Device Code
**Y** = Year Code
**M** = Month Code
(**A**=Jan, **B**=Feb, **C**=Mar, **D**=Apl, **E**=May, **F**=Jun, **G**=Jul, **H**=Aug, **I**=Sep, **J**=Oct, **K**=Nov, **L**=Dec)
**L** = Lot Code

## Notice

Specifications of the products displayed herein are subject to change without notice. TSC or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies.

Information contained herein is intended to provide a product description only. No license, express or implied, to any intellectual property rights is granted by this document. Except as provided in TSC's terms and conditions of sale for such products, TSC assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of TSC products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify TSC for any damages resulting from such improper use or sale.

# Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Taiwan Semiconductor:

TSM3454CX6